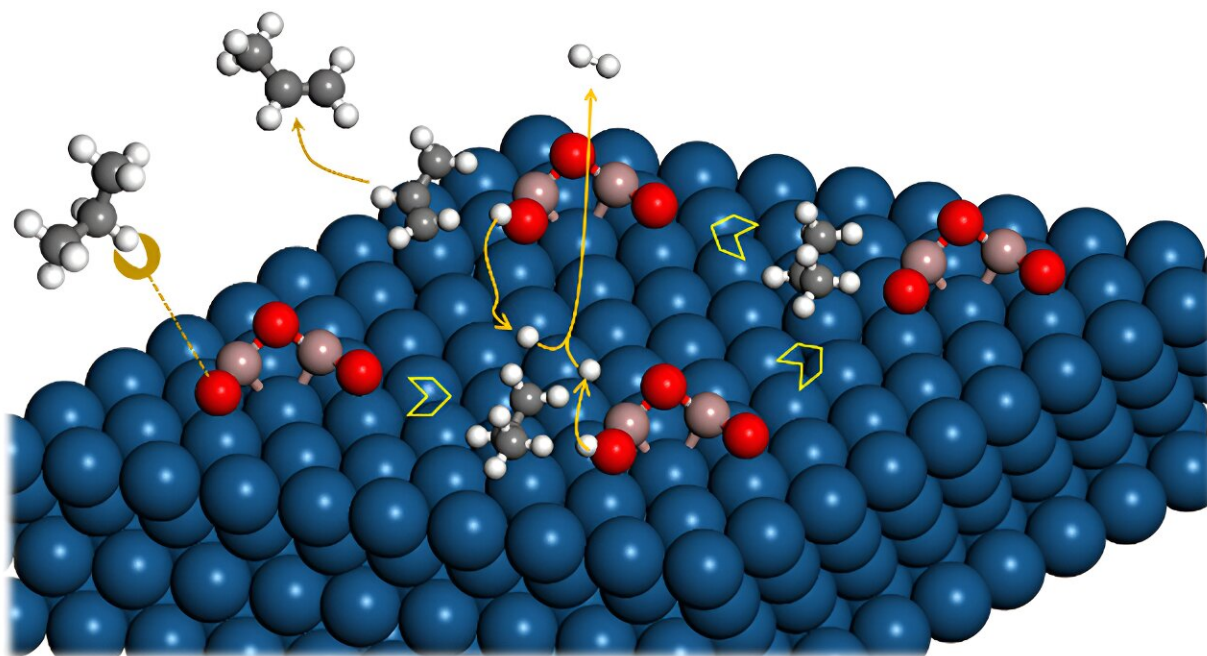


Electronic perturbation-promoted interfacial pathway for facile C–H dissociation

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Ga₂O₃ species on Pt (111) act as a bridge to facilitate dehydrogenation. This involves the ionization of the propane molecule followed by smooth H spillover and subsequent H₂ desorption. The electronic perturbation at the Pt-Ga₂O₃ interface induces higher-lying O 2p states, accompanied by a substantial density of states around the Fermi level. This leads to an exceptionally strong affinity for H and a robust ability for C–H scission. Credit: *Chinese Journal of Catalysis*

Pt-based catalysts have been extensively employed in catalytic propane dehydrogenation (PDH) processes, playing a crucial role in propylene

production. However, monometallic Pt catalysts often exhibit inferior propylene selectivity due to the hydrogenolysis, rapid deactivation from coke deposits, and nanoparticle sintering. To address these challenges, various metals (Sn, Zn, Ga, Co, etc.) have been introduced to enhance the selectivity and stability of Pt-based catalysts.

Typically, the formation of metal alloys, responsible for modulating the geometric and electronic structure of Pt, is considered a primary factor contributing to improved performance. Nevertheless, this modification tends to suppress the ability of Pt to activate C-H bonds, a critical aspect in dehydrogenation reactions.

The activation of strong C-H bonds within alkane molecules demands a significant energy input, resulting in relatively high barriers for the dehydrogenation process. To further enhance the catalytic efficiency of Pt-based catalysts in PDH, a more intricate design of active centers with a robust ability to activate propane and a high selectivity for propylene remains a necessary endeavor.

Recently, a research team led by Prof. Yong Wang from Zhejiang University, China, reported a remarkably efficient interfacial pathway for facile C-H bond scission at the Pt-GaO_x interface by inducing O sites through electronic disturbance of Pt. Ga₂O₃ species on Pt (111) act as a bridge, enabling easy dehydrogenation.

This process involves the ionization of the propane molecule to a proton and a mild alkyl shift, followed by smooth H spillover at high temperatures. Importantly, this mechanism differs significantly from the radical mechanism observed on monometallic and/or alloyed Pt surfaces.

The results have been [published](#) in the *Chinese Journal of Catalysis*.

Density functional theory calculations reveal that the oxygen sites of

Ga₂O₃ species on the Pt surface exhibit higher-lying O 2p states and a considerable density of states around the Fermi level due to the electronic disturbance of the underlying Pt.

Consequently, these sites display a pronounced affinity for H and an exceptionally low energy barrier (less than 0.30 eV) for C-H dissociation. Furthermore, the Ga oxide component also contributes to the modification of the geometric structure of Pt nanoparticles. This modification leads to a reduction in ensemble size, promoting the selective production of propylene.

The designed Pt/Ga-Al₂O₃ catalysts demonstrate their superior performance in the PDH reaction compared to benchmark PtSn/Al₂O₃ catalysts.

More information: Zhe Wang et al, Electronic perturbation-promoted interfacial pathway for facile C–H dissociation, *Chinese Journal of Catalysis* (2024). DOI: [10.1016/S1872-2067\(23\)64575-9](https://doi.org/10.1016/S1872-2067(23)64575-9)

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